RENESAS

Data Flash Access Library

Type T04 (Pico), European Release

16 Bit Single-chip Microcontroller
RL78 Series

Installer: RENESAS_FDL_RL78_T04E_Vx.xxx

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Preface

Readers   This manual is intended for users who want to understand the functions of the concerned libraries.

Purpose   This manual presents the software manual for the concerned libraries.

Organization   This document describes the following sections:

- Architecture
- Implementation and Usage
- API

Note   Additional remark or tip

Caution   Item deserving extra attention

Numeric notation

Binary:	xxxx or xxxB
Decimal:	xxxx
Hexadecimal	xxxxH or 0x xxxx

Numeric prefixes   representing powers of 2 (address space, memory capacity):

K (kilo):	$2^{10} = 1024$
M (mega):	$2^{20} = 1024^2 = 1,048,576$
G (giga):	$2^{30} = 1024^3 = 1,073,741,824$

Register contents   X, x = don't care

Diagrams   Block diagrams do not necessarily show the exact software flow but the functional structure. Timing diagrams are for functional explanation purposes only, without any relevance to the real hardware implementation.

How to Use This Manual

(1) Purpose and Target Readers

This manual is designed to provide the user with an understanding of the library itself and the functionality provided by the library. It is intended for users designing applications using libraries provided by Renesas. A basic knowledge of software systems as well as Renesas microcontrollers is necessary in order to use this manual. The manual comprises an overview of the library, its functionality and its structure, how to use it and restrictions in using the library.

Particular attention should be paid to the precautionary notes when using the manual. These notes occur within the body of the text, at the end of each section, and in the Usage Notes section.

The revision history summarizes the locations of revisions and additions. It does not list all revisions. Refer to the text of the manual for details.

(2) List of Abbreviations and Acronyms

Abbreviation	Full Form
API	Application programming interface
BGO	Background operation
Flash Area	Area of Flash consists of several coherent Flash Blocks
Code Flash	Embedded Flash where the application code or constant data is stored.
Data Flash	Embedded Flash where mainly the data of the EEPROM emulation are stored.
Data Set	Instance of data written to the Flash by the EEPROM Emulation Library (EEL), identified by the Data Set ID
DS	Data Set
Dual Operation	Dual operation is the capability to access flash memory during reprogramming another flash memory range. Dual operation is available between Code Flash and Data Flash. Between different Code Flash macros dual operation depends on the device implementatio
ECC	Error correction code
EEL	EEPROM Emulation Library
EEPROM	Electrically erasable programmable read-only memory
EEPROM emulation	In distinction to a real EEPROM the EEPROM emulation uses some portion of the flash memory to emulate the EEPROM behavior. To gain a similar behavior some side parameters have to be taken in account.
FAL	Flash Access Library (Flash access layer)
FCL	Code Flash Library (Code Flash access layer)

Abbreviation	Full Form
FDL	Data Flash Library (Data Flash access layer)
Firmware	Firmware is a piece of software that is located in a hidden area of the device, handling the interfacing to the flash.
Flash	Electrically erasable and programmable nonvolatile memory. The difference to ROM is, that this type of memory can be re-programmed several times.
Flash Block	A flash block is the smallest erasable unit of the flash memory.
Flash Macro	A certain number of Flash blocks is grouped together in a Flash macro.
FW	Firmware
ID	Identifier of a Data Set instance in the Renesas EEPROM Emulation
NVM	Non volatile memory. All memories that hold the value, even when the power is cut off. E.g. Flash memory, EEPROM, MRAM...
PFDL	Pico FDL
RAM	"Random access memory" - volatile memory with random access
REE	Renesas Electronics Europe GmbH
REL	Renesas Electronics Japan
REN	Renesas Electronics Corporation
ROM	"Read only memory" - nonvolatile memory. The content of that memory can not be changed.
Segment / Section	Segment of Flash is a part of the flash that might consist of several blocks. Important is, that this segment can be protected against manipulation.
Self-Programming	Capability to reprogram the embedded flash without external programming tool only via control code running on the microcontroller.
Sequencer	Dedicated circuit controlling the flash memory (integral part of RL78 device with data flash)
Serial programming	The onboard programming mode is used to program the device with an external programmer tool.
SPL	Flash Self-programming Library

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Table of Contents

Chapter 1 Overview

A Data Flash Library (FDL) is a software library to perform operations on the data flash memory on the RL78 microcontroller.

The library described in this manual (RL78 Data Flash Library Type 04) offers a minimal set of features and aims at very resource critical systems. It is referred to as Pico FDL (PDFL) throughout this document.

Please use this Data Flash Library user's manual together with the user's manual of the target RL78 microcontroller.

1.1 Important Terms

The following important terms and definitions are used throughout this manual:

- *Data Flash Library (FDL)*
  Library for data flash memory operations utilizing the features provided by the RL78 microcontroller family.
  The library cannot operate on the code flash memory.

- *Flash Self-programming Library (SPL)*
  Library for code flash memory operation utilizing the features provided by the RL78 microcontroller.
  Operations on the data flash memory cannot be performed.

- *EEPROM Emulation Library*
  Library that provides functions to store data in the built-in flash memory in an EEPROM-like fashion.

- *Block number*
  Number that identifies a block of the flash memory. It is the unit of erasure operations in the Data Flash Library Type 04.

- *Internal verification*
  Is used to check if the signal level of the flash memory cell is appropriate after writing to the flash memory in order to ensure full data retention.

- *Sequencer*
  The RL78 microcontroller features a dedicated circuit for controlling the flash memory. In this document, this circuit is called "sequencer."

- *Background operation (BGO)*
  State in which rewriting of the flash memory can be done while operating the user program by letting the sequencer control the flash memory. For a more detailed description, please refer to "2.1 Hardware Environment" and "3.4 Background Operation (BGO)."

- *Status check*
  Using the sequencer in BGO requires to check the state of the sequencer (state of control for the flash memory) within the program controlling the flash memory. In this document, the processing to check the state of the sequencer is called "status checking."

1.2 Basic Workflow

In order to perform rewriting of the data flash memory with the PFDL, the initialization process for the library needs to be executed first. Afterwards, the actual accesses to the data flash can be performed by means of dedicated API functions.

The PFDL provides APIs for the C and assembly language of the CA78K0R, IAR, GNU and CC-RL tool chains.

1.2.1 Library States and Transitions

During operation, the PFDL passes through several states as illustrated in the diagram presented in Figure 1-1.

Figure 1-1
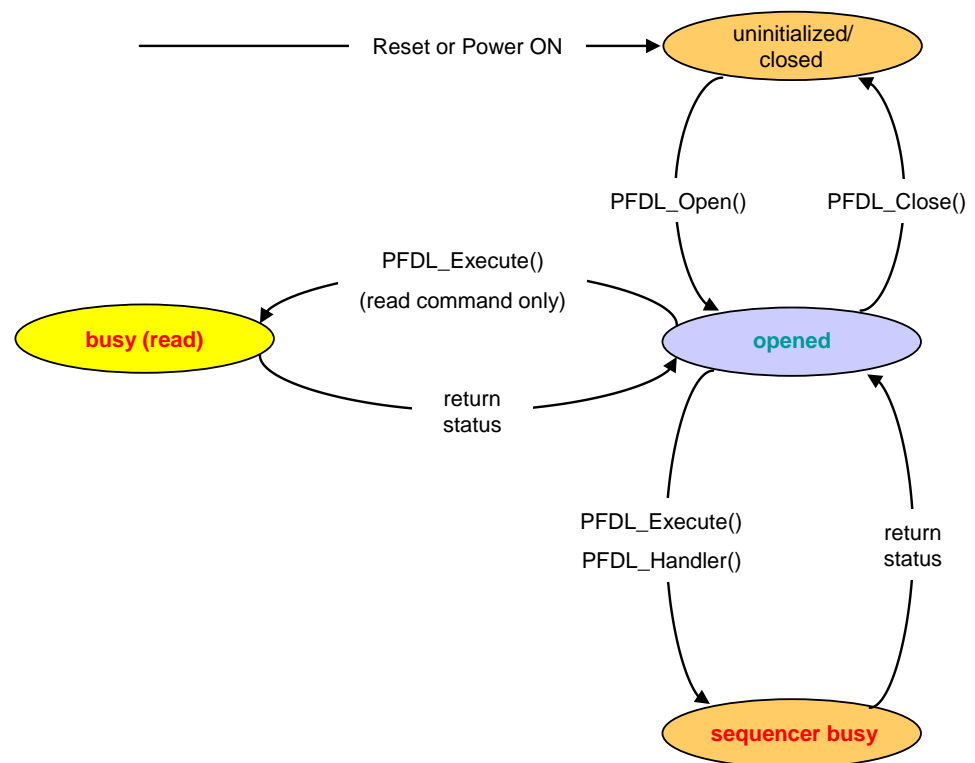
State transition diagram of Data Flash Library Type 04

To operate the data flash memory by using the PFDL, the provided functions need to be executed sequentially. Thereby, the library state can be controlled. A detailed description of each state is given below:

1. *uninitialized/closed*
   State at Power ON and Reset. In this state, the Pico FDL is disabled. Please drive the library to this state via PFDL_Close whenever you want to

   • execute the Flash Self-programming Library,

   • run an EEPROM Emulation Library,

   • use a Data Flash Library other than Type 04 (PFDL), or

   • utilize a STOP or HALT command.

   Please note that the execution of PFDL_Close has to be completed before any of these listed actions can be taken.

2. *opened*
   State in which the PFDL_Open function has been executed from the uninitialized/closed state and the Data Flash Library is operational.

3. *busy (read)*
   State in which the specified processing is being executed directly by the library. The control does not return to the user program until the processing is completed. Please note that the transition to this state is only triggered by the read command in the PFDL.

4. *sequencer busy*
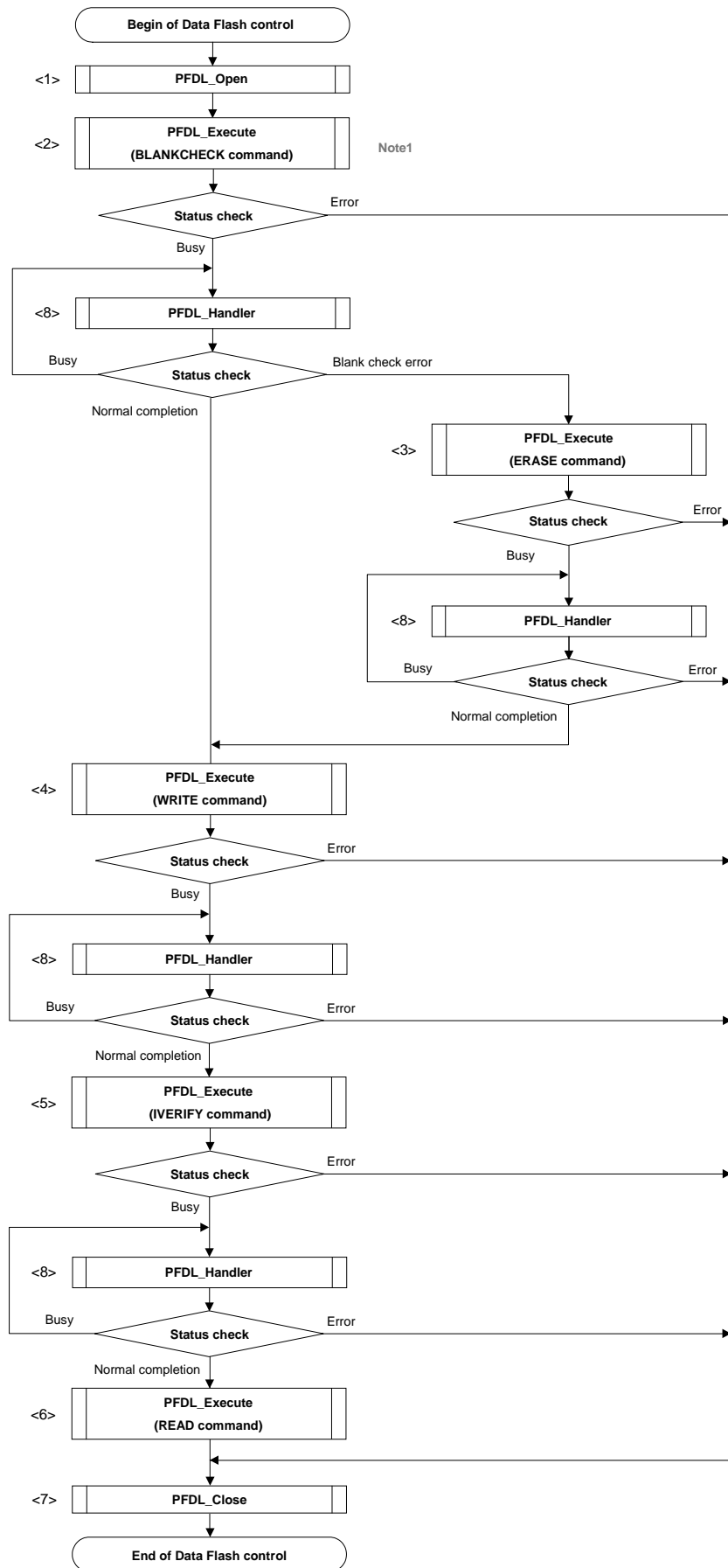   State in which the specified processing is being executed with the sequencer. The PFDL_Execute function is used to trigger various commands to be executed on the data flash memory and returns to the user program without waiting for the completion of the sequencer operation. The current status of a running operation in the sequencer can be checked and driven forward with the PFDL_Hander function.

1.2.2 Exemplary Flow

Figure 1-2 shows an example of the data flash memory rewriting flow by using the PFDL. In the following, a more detailed description is given of the illustrated steps:

<1> Initializing the PFDL
The PFDL_Open function is called to initialize the RAM used for the PFDL and to enable the library.

<2> Blank checking 1 to 1024 bytes for the specified address (PFDL_CMD_BLANKCHECK_BYTES command)
The PFDL_Execute function (with the PFDL_CMD_BLANKCHECK_BYTES command specified) is called to perform blank checking of 1 to 1024 bytes for the specified address. The processing cannot be executed across blocks.

<3> Erasing the specified block (1 KB) (PFDL_CMD_ERASE_BLOCK command)
The PFDL_Execute function (with the PFDL_CMD_ERASE_BLOCK command specified) is called to erase the specified block (1 KB).

<4> Writing 1 to 1024-byte data to the specified address (PFDL_CMD_WRITE_BYTES command)
The PFDL_Execute function (with the PFDL_CMD_WRITE_BYTES command specified) is called to write 1 to 1024 bytes to the specified address. The processing cannot be executed across blocks.

<5> Internal verification of 1 to 1024 bytes for the specified address (PFDL_CMD_IVERIFY_BYTES command)
The PFDL_Execute function (with the PFDL_CMD_IVERIFY_BYTES command specified) is called to perform internal verification of 1 to 1024 bytes for the specified address. The processing cannot be executed across blocks.

<6> Reading 1 to 1024 bytes from the specified address (PFDL_CMD_READ_BYTES command)
The PFDL_Execute function (with the PFDL_CMD_READ_BYTES command specified) is called to read 1 to 1024 bytes for the specified address. All the processing of reading is executed within the PFDL_Execute function.

<7> Ending the PFDL operation
The PFDL_Close function is called to end the operation of the PFDL.

<8> Status checking
The PFDL_Handler function is called to perform status checking and drive a running command. Status checking must be performed until the control to the data flash memory by the sequencer is finished.

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Figure 1-2

Begin of Data Flash control

<1> PFDL_Open

<2> PFDL_Execute (BLANKCHECK command) — Note1

Status check — Error

Busy

<8> PFDL_Handler

Status check — Blank check error

Busy

Normal completion

<3> PFDL_Execute (ERASE command)

Status check — Error

Busy

<8> PFDL_Handler

Status check — Error

Busy

Normal completion

<4> PFDL_Execute (WRITE command)

Status check — Error

Busy

<8> PFDL_Handler

Status check — Error

Busy

Normal completion

<5> PFDL_Execute (IVERIFY command)

Status check — Error

Busy

<8> PFDL_Handler

Status check — Error

Busy

Normal completion

<6> PFDL_Execute (READ command)

<7> PFDL_Close

End of Data Flash control

Exemplary flow of Data Flash operation using the PFDL

Note 1 Please note that the presented flow is only an example. It is *not* mandatory to perform a blankcheck before an erase, if you are sure that you want to erase the block in any case. The erase command performs an automatic blankcheck. Please see Section 3.7.5 for details.
For a regular write however, please follow the suggested sequence of blankcheck/write/iverify in order to ensure full data retention.

A detailed description of all PFDL API functions can be found in Section 3.6, while all commands that can be triggered via PFDL_Execute are explained in Section 3.7.

Chapter 2 Programming Environment

This chapter describes the hardware environment and software environment required to rewrite the data flash memory using the Data Flash Library Type 04 (PFDL).

2.1 Hardware Environment

The PFDL for the RL78 microcontroller uses the sequencer to control the Data Flash memory. As the sequencer has the direct control to the data flash memory, the user program can be operated in parallel to the data flash memory control. This is called BGO (background operation).

During rewriting of the data flash memory, the data flash memory is blocked for other accesses. However, the code flash memory can be accessed, so interrupt processing, the user program, and the PFDL can be allocated in the ROM for operation as usual.

The access restrictions during data flash operations are depicted in Figure 2-1.

Figure 2-1

On-chip RAM

Data flash memory

Reading cannot be executed during data flash memory control.

The user program can operate as usual with the BGO (back-ground operation) during data flash memory control.

Code flash memory

Interrupts can be used as usual.
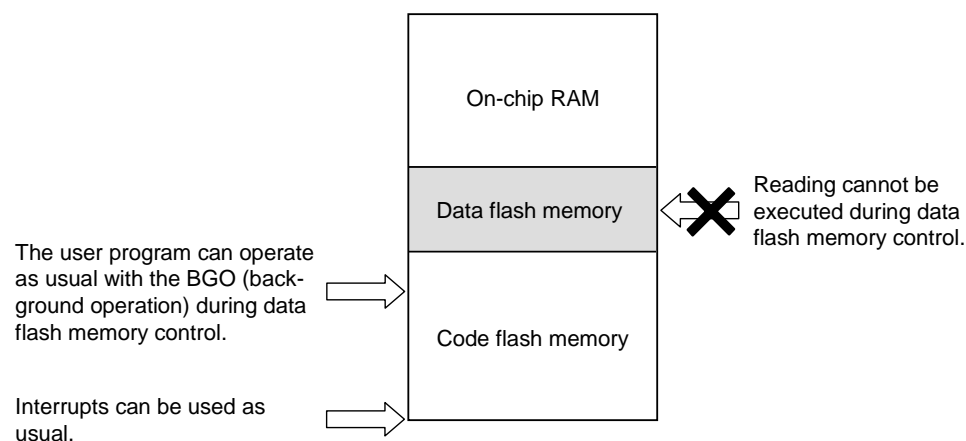
Access restrictions during Data Flash operation

Figure 2-2 shows an example of execution of the Data Flash Library function to perform rewriting of the data flash memory.

After an execution request has been send to the sequencer of the RL78 microcontroller via the PFDL API, the control is immediately returned to the user program. For the current state and result of the issued FDL command, the status check function (PFDL_Handler function) must be called repeatedly from the user program. Please note that there are commands which require a calling PFDL_Handler to drive the command execution (see Section 3.4 for details). The actual number of handler calls required to finish a command is not predictable as it depends on the type of command, the parameters and the time interval between the calls.

Figure 2-2
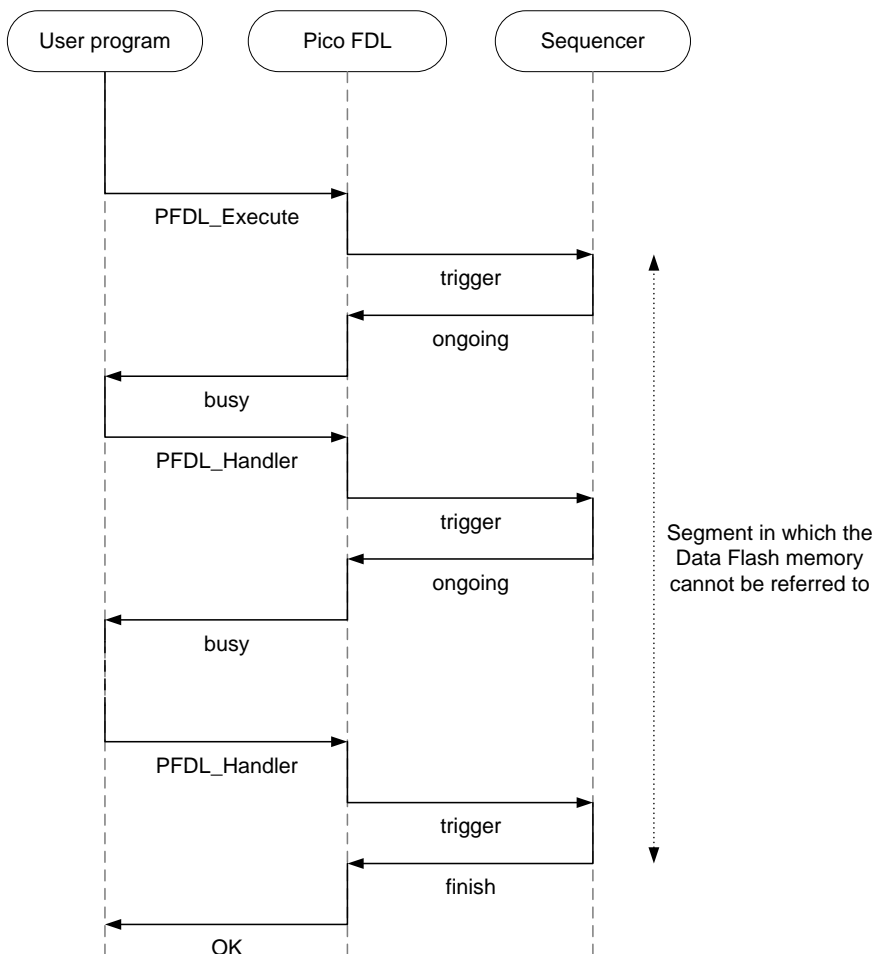
Exemplary sequencer control via PFDL

2.1.1 Initialization

Before accessing the Data Flash memory by using the PFDL, the following settings need to be performed:

1. *Starting the high-speed on-chip oscillator*
   During the usage of the PFDL, keep the high-speed on-chip oscillator running. When the oscillator is stopped, start the oscillator before using the PFDL.

2. *Setting the CPU operating frequency*[Note1]
   In order to perform the timing calculation used in the PFDL, set the CPU operating frequency during the initialization. A detailed description of the method that can be used to set the frequency can be found in Section 3.6.1 PDFL_Open.

3. *Setting voltage mode*[Note2]
   In order to specify the voltage mode when writing the data flash memory, select one of the following modes during the initialization.
   - Full-speed mode
   - Wide voltage mode
   A detailed description of the method that can be used to set the voltage mode can be found in Section 3.6.1 PDFL_Open.

Note 1 The CPU operating frequency is used for the parameters of the timing calculation within the PFDL. The actual frequency of the processor core is not changed.

Note 2 For the details of the voltage mode, see the target RL78 microcontroller user's manual.

2.1.2 Blocks

The flash memory of the RL78 microcontroller is divided into 1-KB blocks. In the Data Flash Library, erasure processing is performed for the data flash memory in the units of the blocks.

Reading, writing, blank checking or internal verification are performed on byte granularity and require the specification of start address[Note] and size.

Figure 2-3 shows an example of block positions and block numbers of the data flash memory.

Note The address value is used when reading/writing data from/to the flash memory. The address is specified relative to the first element of block 0 of the data flash memory. Note that the specified address is not an absolute address.

Figure 2-3
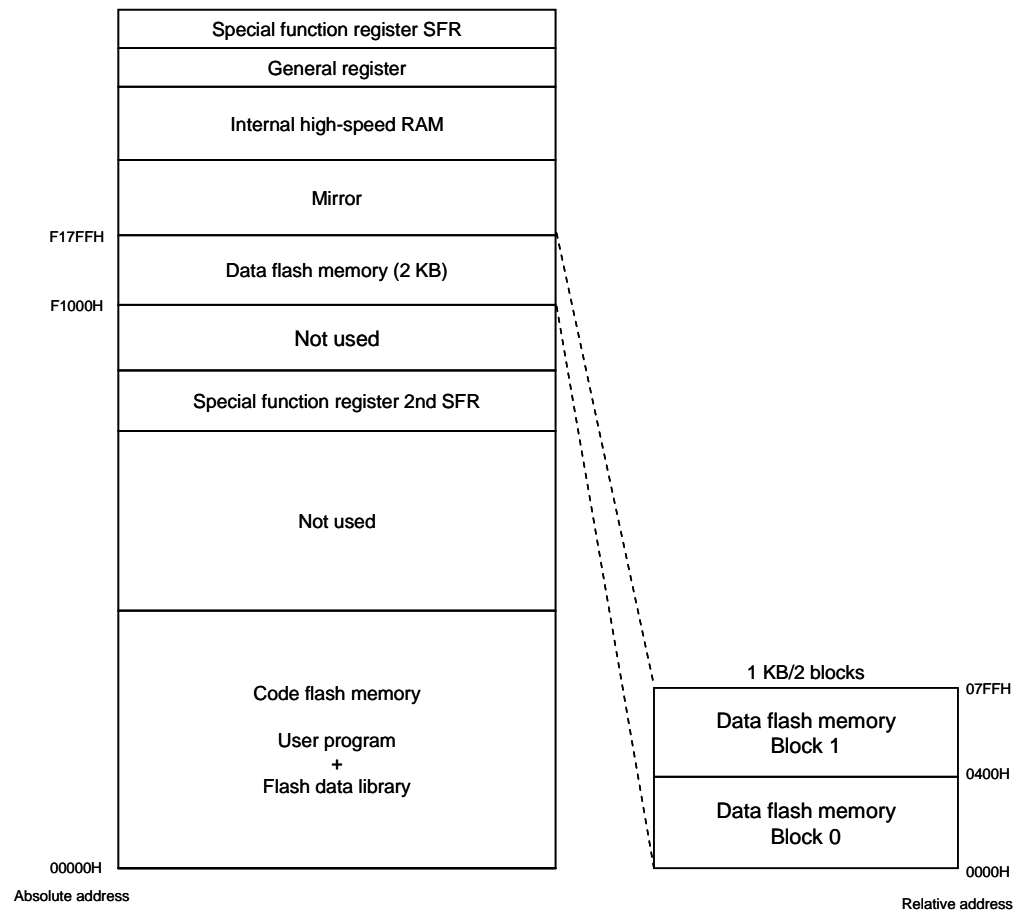
Blocks of Data Flash Memory (here: RL78/G12 with 2 KB Data Flash)

2.2 Software Environment

The PFDL is allocated together with the program in the user area, occupying an area equal to the size of the library. Furthermore, the library itself uses the CPU, the stack, and a data buffer.

Detailed information about the required software resources is listed in Table 2-1.

Table 2-1   **Resource consumption[Note1]**

	CA78K0R	**IAR**	**GNU**	**CC-RL**
Max code size (program area)	175 bytes	180 bytes	199 bytes	168 bytes
Constants (program area)	-	-	-	-
Internal data	-[Note2]	-[Note2]	-[Note2]	-[Note2]
Max. stack consumption	46 bytes	46 bytes	50 bytes	40 bytes

Note1   All values for resource consumption are based on PFDL version V1.04.

Note2   Depending on the used device, the PFDL may use a fraction of the user RAM as working area. Size and location of this area is strictly device dependent, see Section 2.2.2 for more details.

2.2.1 File Structure

The actual file structure for the Data Flash Library T04 depends on the utilized tool chain and is listed separately for CA78K0R, IAR, GNU and CC-RL in Table 2-2, Table 2-3 and Table 2-4, respectively.

Please note that assembler header files for GNU use the same extension '.h' as C header files, because the C preprocessor can and should be used for assembler files in the GNU tool chain.

Table 2-2   **File structure for CA78K0R tool chain**

\<root>	
release.txt	Library release notes
\<root>\lib	
pfdl.h	PFDL interface definition (Compiler)
pfdl_types.h	PFDL types definition (Compiler)
pfdl.inc	PFDL interface definition (Assembler)
pfdl.lib	Pre-compiled library
\<root>\smp	
pfdl_sample_linker_file.dr	Sample linker file

Table 2-3   **File structure for IAR tool chain**

<root>	
release.txt	Library release notes
<root>\lib	
pfdl.h	PFDL interface definition (Compiler)
pfdl_types.h	PFDL types definition (Compiler)
pfdl.inc	PFDL interface definition (Assembler)
pfdl.r26	Pre-compiled library
<root>\smp	
pfdl_sample_linker_file.xcl	Sample linker file

Table 2-4   **File structure for GNU tool chain**

<root>	
release.txt	Library release notes
<root>\lib	
pfdl.h	PFDL interface definition (Compiler)
pfdl_types.h	PFDL types definition (Compiler)
pfdl_asm.h	PFDL interface definition (Assembler)
pfdl.a	Pre-compiled library
<root>\smp	
pfdl_sample_linker_file.ld	Sample linker file

Table 2-5   **File structure for CC-RL tool chain**

<root>	
release.txt	Library release notes
<root>\lib	
pfdl.h	PFDL interface definition (Compiler)
pfdl_types.h	PFDL types definition (Compiler)
pfdl.inc	PFDL interface definition (Assembler)
pfdl.lib	Pre-compiled library
<root>\smp	
pfdl_sample_linker_file.sub	Sample linker file

2.2.2 Prohibited RAM Area

The PFDL may use a fraction of the user RAM as working area, referred as prohibited RAM area. The size and position of this area is strictly device dependent (many devices do not even have this area) and vary between the different RL78 products. For details, please refer to the document "User's Manual: Hardware" of your RL78 product.

If a prohibited RAM area is specified for the utilized device, it is not allowed to access this area while the PFDL is active. Whenever PFDL functions are called, the data in the prohibited area may be rewritten.

2.2.3 Register Bank

The CA78K0R, IAR and CC-RL releases of the PFDL use the registers of the currently selected register bank. No implicit register bank switch is performed by the library.

For the GNU release of the PFDL, it is mandatory that register bank 0 is active on function entry. No implicit register bank switch is performed by the library. Return values are placed in register bank 1. For details on GNU calling conventions, please refer to the GNU documentation for RL78 devices.

Remark   A detailed description of the registers used for parameter passing and return values can be found in Section 3.6 Description of Data Flash Library Functions.

2.2.4 Stack and Data Buffer

The PFDL uses the sequencer to write to the code flash memory, but it uses the CPU for pre-setting and control. Therefore, the PFDL also utilizes the stack specified by the user program.

Remark   To allocate the stack and data buffer to the user-specified address, the link directive is used.

- *Stack*
  In addition to the stack used by the user program, the stack space required for flash functions must be reserved in advance. It has to be ensured that the stack is allocated so that the RAM used by the user will not be destroyed during stack processing of the PFDL. The stack may not be allocated in the short address range from FFE20H to FFEFFH—and also not in the prohibited RAM area, if it exists in the target device.
  For the actual stack space required for the Data Flash Library functions, please refer to Table 2-1.

- *Data buffer*
  The usage of the data buffer is described in following:
  - Work area for internal processing of the PFDL
  - RAM area in which data is located that is to be written into the data flash
  - RAM area in which data is located that is to be obtained from the data flash
  The data buffer may not be allocated in the short address range from FFE20H to FFEFFH—and also not in the prohibited RAM area, if it exists in the target device.

  Please note that the allocation and usage of the data buffer falls into the responsibility of the user. Especially it has to be ensured that the data buffer is not touched by any other part of the user application while a read or write command accessing this buffer is still running.

2.2.5 Data Flash Library

Not all Data Flash Library functions are linked. Only the really utilized Data Flash Library functions are linked[Note].

- *Memory allocation of the PFDL*
  Segments are assigned to the functions and variables used in the PFDL. The used areas of the PFDL can be mapped to specific locations.
  For details, refer to 3.2 Segments of Data Flash Library Functions.

Note For the CA78K0R and CC-RL assembler, linking can be reduced to a subset of the Data Flash Library functions by deleting unnecessary functions from the include file.

2.2.6 Program Area

This is the area in which the PFDL and the user program using the PFDL are located.

Utilizing the PFDL for the RL78 microcontroller, the user program can be operated during rewriting of the Data Flash memory, because the Data Flash memory is controlled by the sequencer in the background (background operation).

For details, refer to the sections of Chapter 3 Data Flash Library Function.

2.2.7 Using the PFDL on the R5F10266 device

For the R5F10266 device, RAM is a scarce resource. The device comes with 256 bytes RAM which cannot be used completely by the PFDL. Hence special care has to be taken for a proper RAM usage by a dedicated linking method.

Note Due to the limited memory resource—especially for the stack—the usage of interrupts is prohibited for the R5F10266 device when the PFDL is used.

Table 2-6 shows the usage for the different RAM areas on the R5F10266 device when using the PFDL.

Table 2-6   **RAM usage for R5F10266 when using PFDL**

Address range	Size (byte)	Description	Usage and Limitations
0xFFE00 – 0xFFE1F	32	Free area	Please allocate your PFDL function arguments, and data buffers in this area.
0xFFE20 – 0xFFEA1	130	Short-address area	Do not allocate any PFDL function argument, data buffer or stack in this area.
0xFFEA2 – 0xFFEDF	62	Stack allocation area	Please allocate the stack into this area when using R5F10266. Please ensure that the stack does not exceed this area (including library and user application, see also Table 2-1).
0xFFEE0 – 0xFFEFF	32	General-purpose register area	Do not allocate any PFDL function argument, data buffer or stack in this area.

2.3 Cautions on the Programming Environment

1. Library code must be located completely in the same 64k flash page.

2. The PFDL library initialization by PFDL_Open must be performed before the execution of PFDL_Close, PFDL_Execute, PFDL_Handler.

3. It is not allowed to read the data flash during a command execution of the PFDL.

4. It is not possible to modify the Data Flash in parallel to a modification of the Code Flash.

5. Do not execute the Flash Self-programming Library, EEPROM Emulation Library, or Data Flash Library other than Type 04 during the execution of the PFDL. When using the Flash Self-programming Library, EEPROM Emulation Library, or Data Flash Library other than Type 04, be sure to execute PFDL_Close to close the PFDL.

6. Do not execute the STOP command mode or HALT command mode during the execution of the PFDL. If the STOP command or HALT command needs to be executed, be sure to execute the PFDL_Close function to close the PFDL.

7. The watchdog timer does not stop during the execution of the PFDL.

8. Do not allocate any PFDL function argument, data buffer or stack used by the Data Flash Library to an address over 0xFFE20 or in the prohibited RAM area (if existent for your target device).

9. When using the data transfer controller (DTC) during the execution of the PFDL, do not allocate the RAM area used by the DTC to an address over 0xFFE20 or in the prohibited RAM area (if existent for your target device).

10. Do not use the RAM area (including the prohibited RAM area) used by the PFDL until the library is closed.

11. Do not execute a Data Flash Library function within interrupt processing because the PFDL does not support multiple executions of a Data Flash Library function.

12. When executing the PFDL within an operating system, do not execute a Data Flash Library function from multiple tasks, because the PFDL does not support multiple executions of a Data Flash Library function.

13. Before initiating any operation with the PFDL, the high-speed on-chip oscillator needs to be started.

14. Note the following regarding the operating frequency of the RL78 microcontroller and the operating frequency value set with the initialization function (PFDL_Open).

    - When a frequency below 4 MHz[Note1] is used as the operating frequency of the RL78 microcontroller, 1 MHz, 2 MHz, or 3 MHz can be used (a frequency such as 1.5 MHz that is not an integer value cannot be used). Also, set an integer value such as 1, 2, or 3 as the operating frequency value set with the initialization function.

    - When a frequency over 4 MHz[Note1] is used as the operating frequency of the RL78 microcontroller, a frequency with decimal places can be used. However, specify a rounded up integer value as the operating frequency set with the initialization function (PFDL_Open).
    Example: For 4.5 MHz, set "5" with the initialization function.

    - The operating frequency is not the frequency of the high-speed on-chip oscillator.

15. The PFDL does not perform error checking of the parameters set in the argument of a Data Flash Library function. Therefore, make sure to set a

correct value to the parameter after checking the specifications of the target RL78 microcontroller. If parameter checking is required to set a correct value, perform it in the user program.

16. Please initialize all function arguments (including unused structure elements) at least once before calling a function. Otherwise, a RAM parity error may cause a reset of the device. For details, please refer to the document "User's Manual: Hardware" of your RL78 product.

17. Do not write to a data flash cell that is not erased. It is prohibited to rewrite a data flash cell without erasing the corresponding data flash block first. The PFDL does not contain any sanity checks to prevent such a situation. The user is responsible to ensure the compliance of this rule.

18. The data flash control register (DFLCTL) should not be operated during the execution of the PFDL. In addition, when the operation of the PFDL is ended, the DFLCTL is set to access inhibit state by the PFDL_Close function.
If accessing the data flash memory is required even after the operation of the PFDL is ended, verify the completion of the PFDL_Close function, set the DFLCTL to the access permit state and perform the setup[Note2].

19. After the execution of PFDL_Close, all requested/running commands will be aborted and cannot be resumed. The user has to take care that all running commands are finished before calling PFDL_Close.

Note 1   For the range of the operating frequency, see the target RL78 microcontroller user's manual.

Note 2   For the method of the setup, see the target RL78 microcontroller user's manual.

Chapter 3 Data Flash Library Function

This chapter describes the details of the Data Flash Library functions.

3.1 Type of Data Flash Library Functions

The PFDL provides the following flash functions as listed in Table 3-1.

Table 3-1   **List of Data Flash Library functions**

Function name	Description
PFDL_Open	Initialization of the RAM used by the PFDL, enabling of the Data Flash clock
PFDL_Close	Ending the operation of the PFD, disabling of the Data Flash clock
PFDL_Execute	Triggering and execution of commands on the Data Flash memory
PFDL_Handler	Checking of the current status of a running Data Flash operation and driving the command forward (status check processing)
PFDL_GetVersionString	Acquisition of the version information of the PFDL

3.2 Segments of Data Flash Library Functions

The Data Flash Library functions are located in the following segment:

- PFDL_COD: Segment of the Data Flash Library functions.
                          It can be allocated to the ROM or RAM.

3.3 Commands

All flash operations are issued in the PFDL via the PFDL_Execute function. The command specified as argument of PFDL_Execute determines the type of the flash operation. Table 3-2 lists all available commands. For details on the execution method, please refer to Section 3.6.3.

Table 3-2   **List of commands specified for PFDL_Execute (pfdl_command_t)**

Definition	Value	Command name
PFDL_CMD_READ_BYTES	0x00	Read command
PFDL_CMD_BLANKCHECK_BYTES	0x08	Blank check command
PFDL_CMD_ERASE_BLOCK	0x03	Erasure command
PFDL_CMD_WRITE_BYTES	0x04	Write command
PFDL_CMD_IVERIFY_BYTES	0x06	Internal verification command

3.4 Background Operation (BGO)

The Data Flash Library functions can be divided into functions that do not use the sequencer and functions that use the sequencer[Note]. For the functions that use the sequencer[Note], background operation (BGO) can be performed.

The following Figure 3-1 and Figure 3-2 show examples of operation of the PFDL during BGO. Please note that especially for a write command it is mandatory to call the PFDL_Handler not only to check the command progress, but also to drive the command.

Table 3-3 shows a list of the API functions with their relation to the sequencer control.

Note Not during the execution of the PFDL_CMD_READ_BYTES command.

Figure 3-1
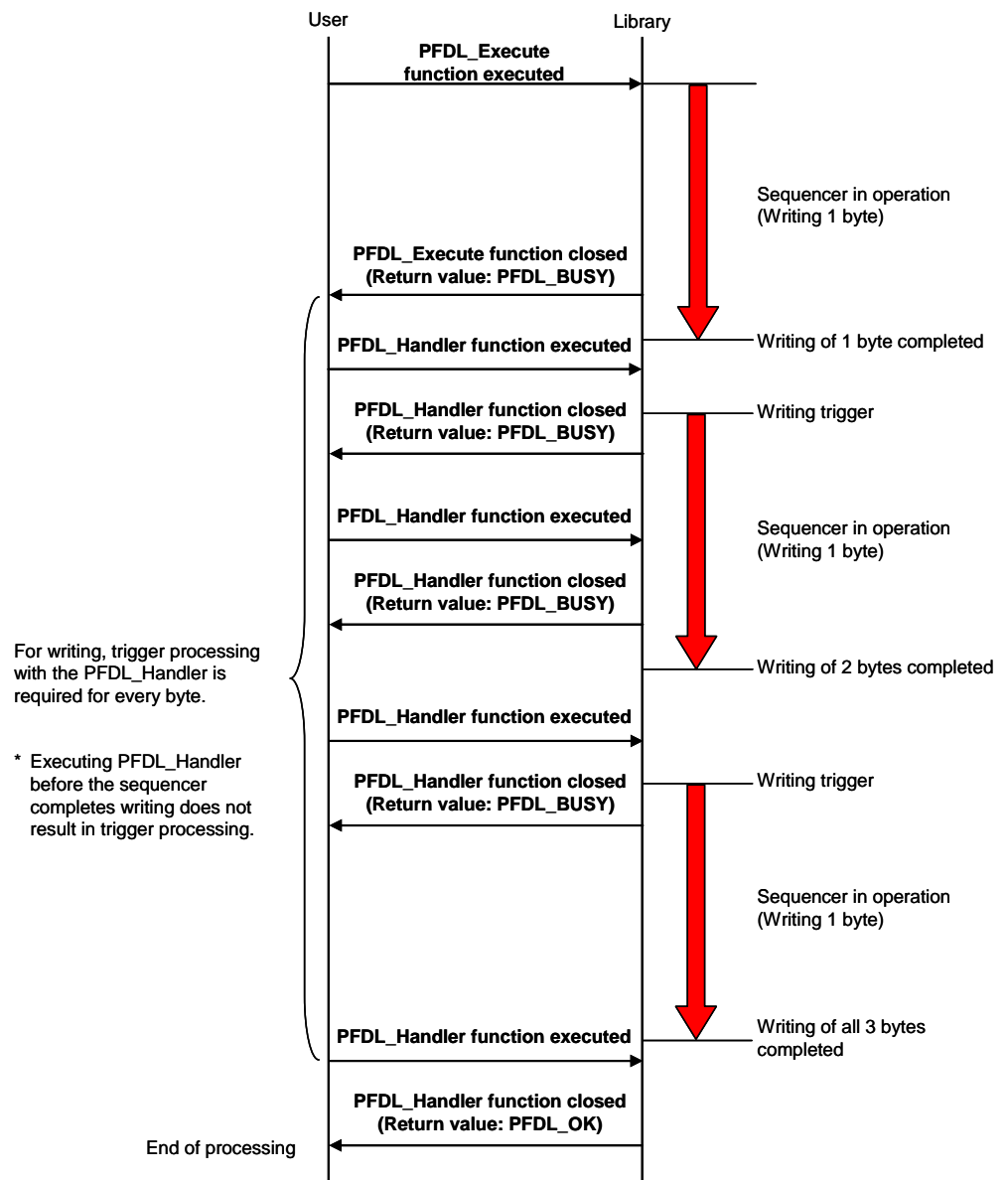
Background operation example 1 (write: 3 byte)

Figure 3-2

```
                                    User                           Library

                              PFDL_Execute function
                                   executed

                             PFDL_Execute function closed
                             (Return value: PFDL_BUSY)

The control returns immediately, so
other processing can be executed.     PFDL_Handler function executed
The state must be checked until the
completion.                          PFDL_Handler function closed          Sequencer in operation
                                     (Return value: PFDL_BUSY)
* Not during the execution of the
  PFDL_CMD_READ_BYTES
  command.                            PFDL_Handler function executed

                             PFDL_Handler function closed
      End of processing        (Return value: PFDL_OK)
```

Background operation example 2 (erase, iverify, blankcheck)

Table 3-3   List of interrupt reception and BGO of Data Flash Library functions

Function name	Sequencer control / BGO function	Interrupt reception
PFDL_Open	No	Allowed
PFDL_Close		
PFDL_Execute	Yes[Note]	
PFDL_Handler		
PFDL_GetVersionString	No	

Note   Not during the execution of the PFDL_CMD_READ_BYTES command.

3.5 List of Data Types, Return Values, and Return Types

The data types are listed in Table 3-4. The return types are specified in Table 3-5, while the meaning of each return value is given in Table 3-6.

Table 3-4   List of data types

Definition	Data type	Description
pfdl_u08	unsigned char	1-byte (8-bit) unsigned integer
pfdl_u16	unsigned int	2-byte (16-bit) unsigned integer
pfdl_u32	unsigned long int	4-byte (32-bit) unsigned integer
pfdl_status_t	enumeration type	set of 1-byte (8-bit) unsigned integer constants (see also Table 3-6)
pfdl_command_t	enumeration type	set of 1-byte (8-bit) unsigned integer constants [Note 1] (see also Table 3-2)
pfdl_request_t	structure	structure to specify requests to be executed on the data flash [Note 1] (see also Table 3-7)
pfdl_descriptor_t	structure	structure to specify the configuration for library initialization [Note 2] (see also Table 3-7)

Note 1   A detailed description can be found in Section 3.6.3 PFDL_Execute.

Note 2   A detailed description can be found in Section 3.6.1 PDFL_Open.

Table 3-5   List of return types

	Return value	
	C language	Assembly language
CA78K0R	pfdl_status_t	C
	__far pfdl_u08*	DE:BC
IAR	pfdl_status_t	A
	pfdl_u08 __far*	A:HL
GNU	pfdl_status_t	R8 (X on bank 1)
	pfdl_u08 __far*	R11:R8 (BC:AX on bank 1)
CC-RL	pfdl_status_t	A
	__far pfdl_u08*	A:DE

Table 3-6   List of pfdl_status_t values

Definition	Return value	Description
PFDL_OK	0x00	Normal completion
PFDL_ERR_PROTECTION	0x10	Reserved for future usage
PFDL_ERR_ERASE	0x1A	Erasure error • Erasure of the target area failed.

Definition	Return value	Description
PFDL_ERR_MARGIN	0x1B	Blank check error or Internal verification error • The target area is not in the blank state. • An error occurred during internal verification processing of the target area.
PFDL_ERR_WRITE	0x1C	Writing error • Writing to the target area failed.
PFDL_IDLE	0x30	Idle state • No command is executed in the PFDL_Execute function.
PFDL_BUSY	0xFF	Execution start of the PFDL_Execute function command, or in execution • The command specified in the PFDL_Execute function is in execution.
Other than above	Other than above	Other error • An abnormal return value. Check the specified command or resource allocation again.

Table 3-7   **List of structures**

Structure	Member	Description
pfdl_request_t	pfdl_u16 index_u16	Target area • Erasure: block number • Other: start address of the target area
	pfdl_u08* data_pu08 (near)	Pointer to the data buffer for acquisition of data to be written or read. Only used for read/write commands
	pfdl_u16 bytecount_u16	Number of bytes to be transferred starting from the start byte specified in index_u16. The byte count range is from 1 byte to 1024 bytes. Please note, that the execution of the read/write/blankcheck/internal verify command across block boundaries is not allowed. This struct member is not required for the erase command.
	pfdl_command_t command_enu	Command to be executed
pfdl_descriptor_t	pfdl_u08 fx_MHz_u08	CPU frequency
	pfdl_u08 wide_voltage_mode_u08	Voltage mode setting

3.6 Description of Data Flash Library Functions

The flash functions are described in the following format.

Outline   Describes the purpose of the function.

Interface   Describes the C interfaces and assembler labels required to access the function.

Arguments   Describes the parameters, return values and register usage of the function.

Precondition   Describes the conditions that have to be fulfilled before calling the function.

Description   Describes the function details and cautions of this function.

3.6.1 PDFL_Open

Outline Initialization of all internal data and activation of the data flash.

Interface **C interface for CA78K0R compiler**

```
pfdl_status_t __far PFDL_Open(__near pfdl_descriptor_t*
                                            descriptor_pstr);
```

C interface for IAR compiler

```
__far_func pfdl_status_t PFDL_Open(__near pfdl_descriptor_t
                                        __near* descriptor_pstr);
```

C interface for GNU compiler

```
pfdl_status_t PFDL_Open(pfdl_descriptor_t* descriptor_pstr)
                            __attribute__ ((section ("PFDL_COD")));
```

C interface for CC-RL compiler

```
pfdl_status_t __far PFDL_Open(__near pfdl_descriptor_t*
                                            descriptor_pstr);
```

ASM function label for CA78K0R, IAR, GNU and CC-RL assembler

```
PFDL_Open
```

Arguments **Parameters**

Argument	Type	Registers				Description
		CA78K0R	IAR	GNU	CC-RL	
descriptor_pstr	pfdl_descriptor_t* (near)	AX	AX	stack	AX	address of the descriptor variable located in the RAM, defines voltage mode and CPU frequency

Structures

Structure	Member	Description
pfdl_descriptor_t	pfdl_u08 fx_MHz_u08	CPU frequency
	pfdl_u08 wide_voltage_mode_u08	Voltage mode setting

Return value

Type	Registers				Description
	CA78K0R	**IAR**	**GNU**	**CC-RL**	
pfdl_status_t	C	A	R8 (X bank 1)	A	Status of operation, PFDL_OK (only possible value)

Destructed registers

Tool chain	Destructed registers
CA78K0R	AX
IAR	X
GNU	none
CC-RL	X, HL, C

Preconditions The following conditions need to be ensured before using PFDL_Open

- The Flash Self-programming Library, the EEPROM Emulation Library, or any Data Flash Library other than Type 04 are not running or have been closed.

- The high-speed on-chip oscillator is running.

Description By calling PFDL_Open, the Data Flash Library is put into operational state and the data flash of the RL78 device is activated.

PFDL_Open reserves and initializes the prohibited RAM area[Note 1] used for the PFDL. If a prohibited RAM area[Note 1] exists, do not use it until the PFDL is closed.

For correct operation, the voltage mode[Note 2] of the PFDL needs to be specified in the wide_voltage_mode_u08 structure member of the argument pfdl_descriptor_t:

- 00H: Full-speed mode

- 01H: Wide voltage mode

Furthermore, the operating frequency of the CPU needs to be set in the fx_MHz_u08 structure member of the argument pfdl_descriptor_t. This parameter is used for the calculation of timing data in the PFDL[Note 3]. For the value of the operating frequency of the CPU (fx_MHz_u08), note the following:

- When a frequency below 4 MHz[Note 4] is used as the operating frequency of the RL78 microcontroller, only integer frequencies (1 MHz, 2 MHz, or 3 MHz) can be used. Frequencies with decimal fraction (e.g. 1.5 MHz) are not supported. The value of fx_MHz_u08 has to match the actual operating frequency of the device.

- When a frequency over 4 MHz[Note 4] is used as the operating frequency of the RL78 microcontroller, a frequency with decimal franction can be used. However, the fx_MHz_u08 parameter for PFDL_Open needs to be set to the corresponding rounded up integer in this case. (Example: For 4.5 MHz, set a value of "5" with the initialization function.)

- The operating frequency is not the frequency of the high-speed on-chip oscillator.

Note 1 For the prohibited RAM area, refer to the document "User's Manual: Hardware" of your target RL78 microcontroller.

Note 2 For details of the voltage mode, refer to the user's manual of the target RL78 microcontroller.

Note 3 It is a required parameter for timing calculation in the Flash Self-programming Library. This setting does not change the operating frequency of the RL78 microcontroller.

Note 4 For the range of the maximum operating frequency, refer to the document "User's Manual: Hardware" of your target RL78 microcontroller.

3.6.2 PFDL_Close

Outline Ends the operation of the Data Flash Library and drives it into closed state.

Interface **C interface for CA78K0R compiler**

```
void __far PFDL_Close(void);
```

C interface for IAR compiler

```
__far_func  void  PFDL_Close(void);
```

C interface for GNU compiler

```
void  PFDL_Close(void) __attribute__ ((section ("PFDL_COD")));
```

C interface for CC-RL compiler

```
void __far PFDL_Close(void);
```

ASM function label for CA78K0R, IAR, GNU and CC-RL assembler

```
PFDL_Close
```

Arguments no parameters, no return value

Destructed registers

Tool chain	Destructed registers
CA78K0R	none
IAR	none
GNU	none
CC-RL	C

Preconditions Before the execution of this function, the PFDL_Open function must have been completed normally.
Furthermore, all running commands have to be finished before calling PFDL_Close.

Description The function PFDL_Close ends the operation of the Data Flash Library and disables the data flash memory. Please call PFDL_Close whenever you want to

- execute the Flash Self-programming Library,

- run an EEPROM Emulation Library,

- use a Data Flash Library other than Type 04, or

- utilize a STOP or HALT command.

Please note that the execution of PFDL_Close has to be completed before any of these listed actions can be taken.

3.6.3 PFDL_Execute

Outline Executes control commands on the data flash memory.

Interface **C interface for CA78K0R compiler**

```
pfdl_status_t __far PFDL_Execute(__near pfdl_request_t*
                                                request_pstr);
```

C interface for IAR compiler

```
__far_func  pfdl_status_t  PFDL_Execute(__near pfdl_request_t
                                        __near* request_pstr);
```

C interface for GNU compiler

```
pfdl_status_t  PFDL_Execute(pfdl_request_t* request_pstr)
                            __attribute__ ((section ("PFDL_COD")));
```

C interface for CC-RL compiler

```
pfdl_status_t __far PFDL_Execute(__near pfdl_request_t*
                                                request_pstr);
```

ASM function label for CA78K0R, IAR, GNU and CC-RL assembler

```
PFDL_Execute
```

Arguments **Parameters**

Argument	Type	Registers				Description
		CA78K0R	**IAR**	**GNU**	**CC-RL**	
request_pstr	pfdl_request_t* (near)	AX	AX	stack	AX	Address of the structure specifying the flash command to be executed

Structures

Structure	Member	Description
pfdl_request_t	pfdl_u16 index_u16	Target area • Erasure: block number • Other: start address[Note 2] of the target area
	pfdl_u08* data_pu08 (near)	Pointer to the data buffer for acquisition of data to be written or read[Note1] Only used for read/write commands
	pfdl_u16 bytecount_u16	Range of the command specified in bytes[Note1] (starting from the specified start address[Note 2]) Not required for erase commands
	pfdl_command_t command_enu	Command to be executed

Note 1 Specify only for commands requiring the target parameter (if not required, initialize with arbitrary value). The byte count range is from 1 byte to 1024 bytes. Provide the data buffer size for the number of bytes of the data to be written or read. Please note that the specified range may not cross block and has to be specified within one block.

Note 2 The specified address is the relative address that starts from block 0 of data flash memory as address 0. This is not the absolute address.

Figure 3-3
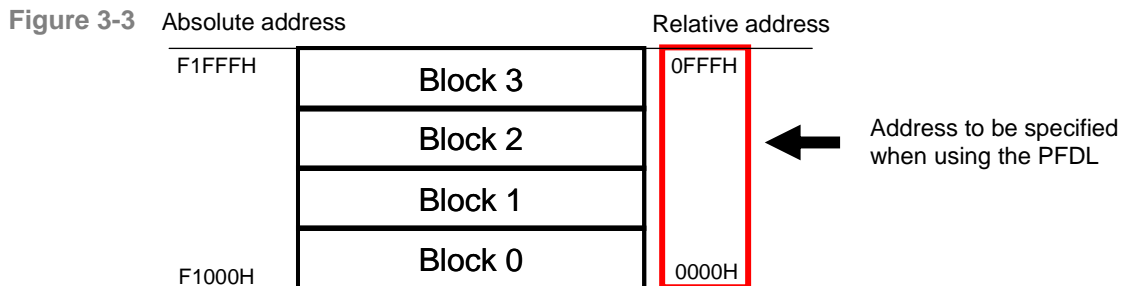
Address specification for commands executed via PFDL_Execute

Return value

Type	Registers				Description
	CA78K0R	**IAR**	**GNU**	**CC-RL**	
pfdl_status_t	C	A	R8 (X bank 1)	A	Status of operation, can be PFDL_BUSY or PFDL_OK

Destructed registers

Tool chain	Destructed registers
CA78K0R	AX
IAR	X
GNU	none
CC-RL	X, BC, DE, HL

Preconditions Before the execution of this function, the PFDL_Open function must be completed normally.

Furthermore, a running command must be finished (via PFDL_Handler) before it is allowed to call PFDL_Execute again.

Although it depends on the command which members of the request structure are necessary for the execution (see Table 3-8), all members of the request variable must be initialized. If there are any unused members in the request variable, the user has to set arbitrary values to these members.

Description The PFDL_Execute function triggers the execution of the specified command on the data flash memory. The available commands are listed in Table 3-8. Please note that – except the read command – all commands are propagated to the sequencer and executed in the background. The final status of the execution needs to be checked via FDL_Handler. A more detailed description of each command can be found in Section 3.7 Description of Data Flash Library Commands.

Table 3-8   List of Execution Commands (pfdl_command_t)

Command	Value	Description
PFDL_CMD_READ_BYTES	0x00	Reads the specified number of bytes from the specified starting address[Note2] in the data flash memory and places it in the read data input buffer. The following arguments must be set for execution: • pfdl_request_t.index_u16: Reading start address[Note2] • pfdl_request_t.bytecount_u16: Read size • pfdl_request_t.data_pu08: Address of the read data input buffer
PFDL_CMD_BLANKCHECK_BYTES	0x08	Performs blank checking from the specified beginning address[Note2] of the data flash memory for the area in the execution range. The following arguments are used[Note3]: • pfdl_request_t.index_u16: Start address[Note2] • pfdl_request_t.bytecount_u16: Execution range from the start address[Note1]
PFDL_CMD_ERASE_BLOCK	0x03	Performs erasure for the block of the specified number in the data flash memory. The following arguments are used[Note3]: • pfdl_request_t.index_u16: Block number

Command	Value	Description
PFDL_CMD_WRITE_BYTES	0x04	Writes the data placed in the write data input buffer to the data flash memory at the specified starting address[Note2] for the specified number of bytes. The following arguments must be set for execution: • pfdl_request_t.index_u16: Write start address[Note2] • pfdl_request_t.bytecount_u16: Write size[Note1] • pfdl_request_t.data_pu0: Address of the write data input buffer
PFDL_CMD_IVERIFY_BYTES	0x06	Performs internal verification starting from the specified beginning address[Note2] of the data flash memory for the area in the execution range. The following arguments are used[Note3]: • pfdl_request_t.index_u16: Start address[Note2] • pfdl_request_t.bytecount_u16: Execution range from the start address[Note1]

Note 1   Cannot be specified across blocks. Specify it within one block.

Note 2   The specified address is the relative address that starts from block 0 of the data flash memory as address 0 when writing and reading the memory. Note that the specified address isn't an absolute address.

Note 3   All members of the request variable must be initialized. Unused members in the request variable can be set to arbitrary values.

3.6.4 PFDL_Handler

Outline Checking of the current processing state of a previously issued command and driving the command forward (especially in case of a write command).

Interface **C interface for CA78K0R compiler**

```
pfdl_status_t __far PFDL_Handler(void);
```

C interface for IAR compiler

```
__far_func  pfdl_status_t PFDL_Handler(void);
```

C interface for GNU compiler

```
pfdl_status_t  PFDL_Handler(void)
                         __attribute__ ((section ("PFDL_COD")));
```

C interface for CC-RL compiler

```
pfdl_status_t __far PFDL_Handler(void);
```

ASM function label for CA78K0R, IAR, GNU and CC-RL assembler

```
PFDL_Handler
```

Arguments **Parameters**

Return value

Type	Registers				Description
	CA78K0R	**IAR**	**GNU**	**CC-RL**	
pfdl_status_t	C	A	R8 (X bank 1)	A	Status of operation, can be PFDL_BUSY, PFDL_OK, PFDL_IDLE, PFDL_ERR_MARGIN, PFDL_ERR_WRITE or PFDL_ERR_ERASE

Destructed registers

Tool chain	Destructed registers
CA78K0R	none
IAR	none
GNU	none
CC-RL	C

Precondition   Before the execution of this function, the PFDL_Open function must be completed normally.

Description   Checks the control state of the command specified in the PFDL_Execute function executed beforehand and performs required settings for continuous execution.

While the status is PFDL_BUSY, the running command is not finished yet and new commands may not be issued. PFDL_OK indicates the successful completion of a command.

The possible error codes depend on the type of the triggered command. Please refer to the individual command descriptions in Section 3.7 Description of Data Flash Library Commands.

3.6.5 PFDL_GetVersionString

Outline Acquisition of the version information of the PFDL.

Interface **C interface for CA78K0R compiler**

```
__far pfdl_u08* __far PFDL_GetVersionString(void);
```

C interface for IAR compiler

```
__far_func pfdl_u08 __far* PFDL_GetVersionString(void);
```

C interface for GNU compiler

```
pfdl_u08 __far* PFDL_GetVersionString(void)
                              __attribute__ ((section ("PFDL_COD")));
```

C interface for CC-RL compiler

```
__far pfdl_u08* __far PFDL_GetVersionString(void);
```

ASM function label for CA78K0R, IAR, GNU and CC-RL assembler

```
PFDL_GetVersionString
```

Arguments **Parameters**

Return value

Type	Registers				Description
	CA78K0R	**IAR**	**GNU**	**CC-RL**	
pfdl_u08* (far)	DE:BC	A:HL	R11..R8 (BC:AX bank 1)	A:DE	Beginning address (24 bit) of the area where the version information of the PFDL is stored as 0-terminated ASCII string.

Destructed registers

Preconditions   none

Description   The function PFDL_GetVersionString can be used to obtain the version information of the utilized library. The version string is given in the following format:

DRL78T04cxx..xyabc

where

- c codes the target compiler for the used library,
  "R" for CA78K0R, "I" for IAR, "U" for GNU and "L" for CC-RL

- xx..x codes the information about the used compiler version and memory model (the length can be between 4 and 5 digits depending on the compiler and release date of the library),

- y identifies the release type, "V" for release, "E" for engineering version,

- abc specifies the library version as Va.bc .

3.7 Description of Data Flash Library Commands

The PFDL offers a set of commands that all can be requested by using the PFDL_Execute function.

Note All commands operate on virtual addresses (relative address that starts from block 0 of the data flash memory as address 0) and block numbers.

3.7.1 PFDL_CMD_READ_BYTES

The read command is used to read a number of bytes from data flash. It is the only command that does not need the sequencer. It is initiated and finished directly by PFDL_Execute.

Status returned by PFDL_Execute

Status	Class	Background and Handling	
PFDL_OK	normal	meaning	request was finished regularly
		reason	no problems during command execution occurred
		remedy	nothing

3.7.2 PFDL_CMD_IVERIFY_BYTES

The internal verify operation is used to check if all bits (0's and 1's) provide full data retention. Inconsistent and weak data caused by an asynchronous reset during a write command can be detected using the iverify command on that specific data range.

The iverify command is initiated by PFDL_Execute and is executed by the sequencer. After that, PFDL_Handler shall be called to complete the command and check the PFDL status.

Status returned by PFDL_Execute

Status	Class	Background and Handling	
PFDL_BUSY	normal	meaning	request is being processed
		reason	request has been accepted
		remedy	call PFDL_Handler until status changes

Status returned by PFDL_Handler

Status	Class	Background and Handling	
PFDL_OK	normal	meaning	request was finished regularly
		reason	no problems during execution
		remedy	nothing
PFDL_ERR_MARGIN	normal	meaning	at least one bit within the specified area could not be verified
		reason	margin for internal verification is below the value required for full data retention
		remedy	no general remedy, the requester has to decide how to react based on application
PFDL_BUSY	normal	meaning	request is being processed
		reason	request has been accepted
		remedy	call PFDL_Handler until status changes

3.7.3 PFDL_CMD_BLANKCHECK_BYTES

The blank-check command is used to check if all cells in the specified target flash area are "erased", e.g. before writing data into it. The user can use the blank-check command freely as it is a non-destructive flash access.

The blank-check command is initiated by PFDL_Execute and is executed by the sequencer. After that, PFDL_Handler shall be called to complete the command and check the PFDL status.

Status returned by PFDL_Execute

Status	Class	Background and Handling	
PFDL_BUSY	normal	meaning	request is being processed
		reason	request has been accepted
		remedy	call PFDL_Handler until status changes

Status returned by PFDL_Handler

Status	Class	Background and Handling	
PFDL_OK	normal	meaning	request was finished regularly
		reason	no problems during execution
		remedy	nothing
PFDL_ERR_MARGIN	light	meaning	at least one bit within the specified area is not blank
		reason	for any bit of the checked area, the margin for an erased cell is below the value required for full data retention
		remedy	no general remedy, the requester has to decide how to react based on the application
PFDL_BUSY	normal	meaning	request is being processed
		reason	request has been accepted
		remedy	call PFDL_Handler until status changes

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3.7.4 PFDL_CMD_WRITE_BYTES

The write command is used to write a number of bytes located in the RAM into the data flash at the location specified by the virtual addresses (relative address that starts from block 0 of the data flash memory as address 0).

The write command is initiated by PFDL_Execute and is executed by the sequencer to perform the physical write. After the write command has been initiated PFDL_Handler shall be called to complete it and to update the library status.

When a write command is issued, the sequencer generates a write-pulse. In case of a fail, the write pulse is repeated. During write-pulse repetition the library state remains busy. In case the write process fails after the maximum internally specified number of retries, an error is returned by a PFDL_Handler call.

Note   For a regular write, please follow the suggested sequence of

- blankcheck

- write

- iverify

as exemplarily shown in Figure 1-2, in order to ensure full data retention.

Status returned by PFDL_Execute

Status	Class	Background and Handling	
PFDL_BUSY	normal	meaning	request is being processed
		reason	request has been accepted
		remedy	call PFDL_Handler until status changes

Status returned by PFDL_Handler

Status	Class	Background and Handling	
PFDL_OK	normal	meaning	request was finished regularly
		reason	no problems during execution
		remedy	nothing
PFDL_ERR_WRITE	heavy	meaning	at least one byte could not be written correctly
		reason	for any bit of the written area, the margin for written data is below the value required for full data retention
		remedy	erase the block and try to write again (caution: erase operates block-wise, ensure to safe other data stored in the block)
PFDL_BUSY	normal	meaning	request is being processed
		reason	request has been accepted
		remedy	call PFDL_Handler until status changes

3.7.5 PFDL_CMD_ERASE_BLOCK

The erase command is used to erase one block of the data flash.

The command is initiated by PFDL_Execute and is executed by the sequencer to perform the physical erase. After the erase command has been initiated PFDL_Handler shall be called to complete it and to update the library status.

In order to avoid unnecessary erase cycles, the hardware sequencer is checking if the addressed block is already blank before starting the actual erase-pulse generation. After that, the erase-command is initiated and finally a block blank-check is executed automatically. This is repeated automatically as long the addressed block is not completely blank. During the complete repetition process the Data Flash Library remains busy. When the maximum internally specified number of erase retries is exceeded an error is returned to the requester.

Status returned by PFDL_Execute

Status	Class	Background and Handling	
PFDL_BUSY	normal	meaning	request is being processed
		reason	request has been accepted
		remedy	call PFDL_Handler until status changes

Status returned by PFDL_Handler

Status	Class	Background and Handling	
PFDL_OK	normal	meaning	request was finished regularly
		reason	no problems during execution
		remedy	nothing
PFDL_ERR_ERASE	heavy	meaning	at least one bit within the specified block is not "blank", the block could not be erased
		reason	for any bit in the addressed flash block, the margin for an erased cell is below the value required for full data retention
		remedy	do not use the block anymore
PFDL_BUSY	normal	meaning	request is being processed
		reason	request has been accepted
		remedy	call PFDL_Handler until status changes

3.8 Library Timings

In the following, certain timing characteristics of the Pico FDL are specified. All timing specifications are based on the

> RL78 FDL T04 V1.04/V1.05

Please note that there might be deviations from the specified timings in case you are using other library versions.

3.8.1 Maximum Function Execution Times

The maximum function execution times are listed in Table 3-9. These timings can be seen as worst case durations of the specific PFDL function calls and therefore can aid the developer for time critical considerations, e.g. when setting up the watchdog timer.

Please note that the function execution times may depend on

- the operating mode (full speed or wide voltage),
- the used clock frequency (given as fclk in MHz), and
- the byte count for the triggered operation (referred to as BYTE_CT).

Table 3-9   Maximum function execution times

Function/Command	Full-speed mode (µs)	Wide-voltage mode (µs)
PFDL_Open	862 / fclk	862 / fclk
PFDL_Execute (erase) Note	536 / fclk	536 / fclk
PFDL_Execute (blank check) Note	484 / fclk	484 / fclk
PFDL_Execute (write) Note	549 / fclk	549 / fclk
PFDL_Execute (iverify) Note	502 / fclk	502 / fclk
PFDL_Execute (read)	(53 / fclk) + (17 / fclk × BYTE_CT)	(53 / fclk) + (17 / fclk × BYTE_CT)
PFDL_Handler	(251 / fclk) + 14	(251 / fclk) + 14
PFDL_Close	(823 / fclk) + 443	(779 / fclk) + 968
PFDL_GetVersionString	(10 / fclk)	(10 / fclk)

Note The execution times listed in Table 3-9 refer to the function call only and not the total time required to complete a command. The execution of erase, blank check, write and iverify commands is only initiated by PFDL_Execute and needs to be completed with successive calls of PFDL_Handler (see also Section 3.4).

3.8.2 Command Execution Times

The command execution times are listed in the following tables. These timings are divided into the typical timings which will appear during the normal operation (Table 3-10) and the maximum timings for worst case considerations (Table 3-11).

All given timings are based on the assumption that the command is executed with continuous PFDL_Handler calls. In case the handler is called too seldom, execution time might increase.

Please note that the command execution times may depend on

- the operating mode (full speed or wide voltage),
- the used clock frequency (given as fclk in MHz), and
- the byte count for the triggered operation (referred to as BYTE_CT).

Table 3-10   **Typical command execution times**

Command	Full-speed mode (µs)	Wide-voltage mode (µs)
Erase	11250 / fclk + 5800	9925 / fclk +7195
Blank check	(906 / fclk + 30) + (5 / fclk + 0.26) × BYTE_CT	(903 / fclk + 62.5) + (4 / fclk + 0.9) × BYTE_CT
Write	(487 / fclk + 11.67) + (212 / fclk + 39.17) × BYTE_CT	(487 / fclk + 11.67) + (208 / fclk + 82.5) × BYTE_CT
Iverify	(621 / fclk + 25) + (23 / fclk + 3.33) × BYTE_CT	(622 / fclk + 48.33) + (14 / fclk + 24.17) × BYTE_CT
Read	(44 / fclk) + (14 / fclk) × BYTE_CT	(44 / fclk) + (14 / fclk) × BYTE_CT

Table 3-11   **Maximum command execution times**

Command	Full-speed mode (µs)	Wide-voltage mode (µs)
Erase	281561 / fclk + 264790	249000 / fclk + 299307
Blank check	(1088 / fclk + 36) + (6 / fclk + 0.31) × BYTE_CT	(1084 / fclk + 75) + (5 / fclk + 1.09) × BYTE_CT
Write	(585 / fclk + 14) + (714 / fclk + 430) × BYTE_CT	(585 / fclk + 14) + (669 / fclk + 954) × BYTE_CT
Iverify	(746 / fclk + 30) + (28 / fclk + 4) × BYTE_CT	(747 / fclk + 58) + (17 / fclk + 29) × BYTE_CT
Read	(53 / fclk) + (17 / fclk × BYTE_CT)	(53 / fclk) + (17 / fclk × BYTE_CT)

Revision History

Chapter	Page	Description
All		Initial document revision 1.00
2.2 2.3	17 19-20	Revision 1.01: Library stack consumption corrected Extension of programming environment precautions
All 2.24 2.2.7 3.8	 19 20 44	Revision 1.10: Adding description of GNU API Extending usage description data buffer Adding dedicated linking method for R5F10266 device Adding maximum function execution times
3.8.2	44-45	Revision 1.11: Adding typical and maximum command execution times.
2.2	17	Revision 1.12 Resource consumption and file structure updated regarding the CC-RL Compiler
3	all	Adding description of CC-RL API
2.3	21-22	Caution chapter extended
all	all	Renesas (REN) Compiler renamed to CA78K0R
3.5/3.6.3	all	Byte count range specification added

Data Flash Access Library

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